

ABSOLUTE MAXIMUM RATINGS

V_{DD} to AGND	–0.5V to 17V
V_{DD} to DGND	–0.5V to 17V
AGND to DGND	–0.5V to $V_{DD} + 0.5V$
DGND to AGND	–0.5V to $V_{DD} + 0.5V$
V_{REF} to AGND, DGND	$\pm 25V$
R_{FB} to AGND, DGND	$\pm 25V$
Digital Inputs to DGND	–0.5V to $V_{DD} + 0.5V$
V_{OUT1} to AGND, DGND	–0.5V to $V_{DD} + 0.5V$
Maximum Junction Temperature	150°C
Operating Temperature Range	
Commercial (K, L Versions)	0°C to 70°C
Industrial (B, C Versions)	–40°C to 85°C
Storage Temperature Range	–65°C to 150°C
Lead Temperature (Soldering, 10 sec)	300°C

PACKAGE/ORDER INFORMATION

TOP VIEW		ORDER PART NUMBER
OUT1	1	20 R_{FB}
AGND	2	19 V_{REF}
DGND	3	18 V_{DD}
DB11 (MSB)	4	17 WR
DB10	5	16 CS
DB9	6	15 DB0 (LSB)
DB8	7	14 DB1
DB7	8	13 DB2
DB6	9	12 DB3
DB5	10	11 DB4
G PACKAGE 20-LEAD PLASTIC SSOP		N PACKAGE 20-LEAD PDIP
SW PACKAGE 20-LEAD PLASTIC SO WIDE		
$T_{JMAX} = XXX^{\circ}C$, $\theta_{JA} = XXX^{\circ}C/W$ (G)		
$T_{JMAX} = 150^{\circ}C$, $\theta_{JA} = 100^{\circ}C/W$ (N)		
$T_{JMAX} = 150^{\circ}C$, $\theta_{JA} = 130^{\circ}C/W$ (SW)		

LTC7545ABG
 LTC7545ABN
 LTC7545ABSW
 LTC7545ACG
 LTC7545ACN
 LTC7545ACSW
 LTC7545AKG
 LTC7545AKN
 LTC7545AKSW
 LTC7545ALG
 LTC7545ALN
 LTC7545ALSW

Consult factory for Military grade parts.

ELECTRICAL CHARACTERISTICS

 $V_{DD} = 5V$ or $15V$, $V_{REF} = 10V$, $V_{OUT1} = AGND = 0V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		LTC7545AK/AB			LTC7545AL/AC			UNITS		
				MIN	TYP	MAX	MIN	TYP	MAX			
Accuracy												
	Resolution			●	12			12		Bits		
INL	Integral Nonlinearity (Relative Accuracy)	(Note 1)	T _A = 25°C T _{MIN} to T _{MAX}	●		±0.5 ±0.5			±0.5 ±0.5	LSB LSB		
DNL	Differential Nonlinearity	Guaranteed Monotonic T _{MIN} to T _{MAX}	T _A = 25°C T _{MIN} to T _{MAX}	●		±1 ±1			±0.5 ±0.5	LSB LSB		
GE	Gain Error	(Note 2)	T _A = 25°C T _{MIN} to T _{MAX}	●		±2 ±3			±1 ±2	LSB LSB		
	Gain Temperature Coefficient	(Note 3)	ΔGain/ΔTemperature	●		1	5		1	5	ppm/°C	
I _{LKG}	OUT1 Leakage Current	(Note 4)	T _A = 25°C T _{MIN} to T _{MAX}	●			±10 ±50			±10 ±50	nA nA	
PSRR	Power Supply Rejection			●			±0.002			±0.002	%/%	
Reference Input												
R _{REF}	V _{REF} Input Resistance	(Note 5)		●	8	11	15		8	11	15	kΩ
AC Performance												
	Output Current Settling Time	(Notes 3, 6, 7)		●			1			1		μs
	Propagation Delay	(Notes 3, 6, 8)		●			150			150		ns
	Digital-to-Analog Glitch Impulse	(Notes 6, 9)		●			5			5		nV-sec
	Multiplying Feedthrough Error	V _{REF} = ±10V, 10kHz Sine Wave		●			5			5		mV _{P-P}
Analog Outputs												
C _{OUT}	Output Capacitance (Note 3)	DB0 to DB11 = 0V, WR, CS = 0V	C _{OUT1}	●		30	70		30	70		pF
		DB0 to DB11 = V _{DD} , WR, CS = 0V	C _{OUT1}	●		60	150		60	150		pF

ELECTRICAL CHARACTERISTICS

$V_{DD} = 5V$, $V_{REF} = 10V$, $V_{OUT1} = AGND = 0V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	ALL GRADES			UNITS	
			MIN	TYP	MAX		
Digital Inputs							
V _{IH}	Digital Input High Voltage		●	2.4		V	
V _{IL}	Digital Input Low Voltage		●		0.8	V	
I _{IN}	Digital Input Current		●	0.001	±1	μA	
C _{IN}	Digital Input Capacitance	(Note 3) V _{IN} = 0V	●		8	pF	
Timing Characteristics (Note 3)							
t _{CS}	$\overline{CS}$ to $\overline{WR}$ Setup Time		●	100		ns	
t _{CH}	$\overline{CS}$ to $\overline{WR}$ Hold Time		●	0		ns	
t _{WR}	Write Pulse Width		●	100		ns	
t _{DS}	Data Setup Time		●	100		ns	
t _{DH}	Data Hold Time		●	5		ns	
Power Supply							
V _{DD}	Supply Voltage		●	4.75	5	5.25	V
I _{DD}	Supply Current	All Digital Inputs = V _{IH} or V _{IL}	●			2	mA
		All Digital Inputs = 0V or V _{DD}	●		10	100	μA

$V_{DD} = 15V$, $V_{REF} = 10V$, $V_{OUT1} = AGND = 0V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	ALL GRADES			UNITS	
			MIN	TYP	MAX		
Digital Inputs							
V _{IH}	Digital Input High Voltage		●	13.5		V	
V _{IL}	Digital Input Low Voltage		●		1.5	V	
I _{IN}	Digital Input Current		●		±1	μA	
C _{IN}	Digital Input Capacitance	(Note 3) V _{IN} = 0V	●		8	pF	
Timing Characteristics (Note 3)							
t _{CS}	$\overline{CS}$ to $\overline{WR}$ Setup Time		●	75		ns	
t _{CH}	$\overline{CS}$ to $\overline{WR}$ Hold Time		●	0		ns	
t _{WR}	Write Pulse Width		●	75		ns	
t _{DS}	Data Setup Time		●	60		ns	
t _{DH}	Data Hold Time		●	5		ns	
Power Supply							
V _{DD}	Supply Voltage		●	14.25	15	15.75	V
I _{DD}	Supply Current	All Digital Inputs = V _{IH} or V _{IL}	●			2	mA
		All Digital Inputs = 0V or V _{DD}	●		10	100	μA

The ● denotes specifications which apply over the full operating temperature range.

Note 1: $\pm 0.5LSB = \pm 0.012\%$ of full scale.

Note 2: Using internal feedback resistor.

Note 3: Guaranteed by design, not subject to test.

Note 4: I_{OUT1} with DAC register loaded to all 0s.

Note 5: Typical temperature coefficient is 100ppm/°C.

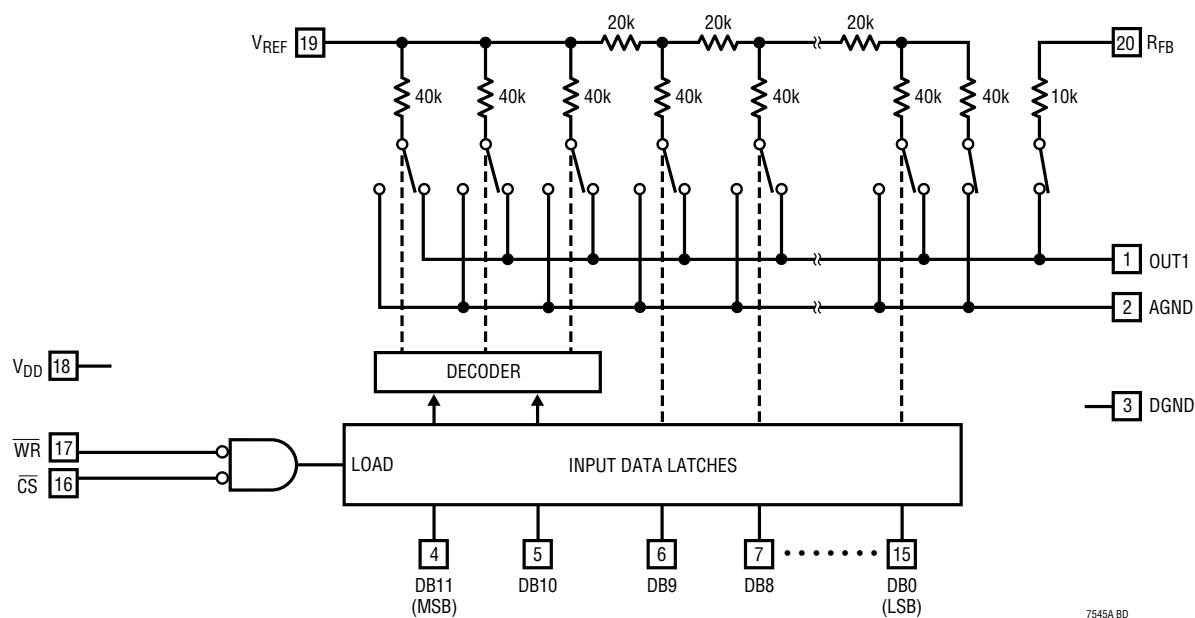
Note 6: $OUT1$ load = 100Ω in parallel with 13pF.

Note 7: To 0.01% for a full-scale change, measured from the falling edge of $\overline{WR}$, $\overline{CS} = 0V$.

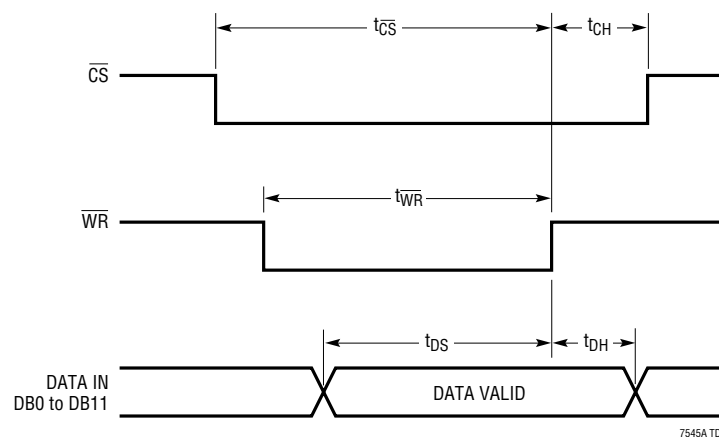
Note 8: From digital input change to 90% of final analog output.

Note 9: $V_{REF} = 0V$. DAC register contents changed from all 0s to all 1s or all 1s to all 0s.

BLOCK DIAGRAM



TIMING DIAGRAM



TYPICAL APPLICATIONS

Unipolar Operation (2-Quadrant Multiplication)

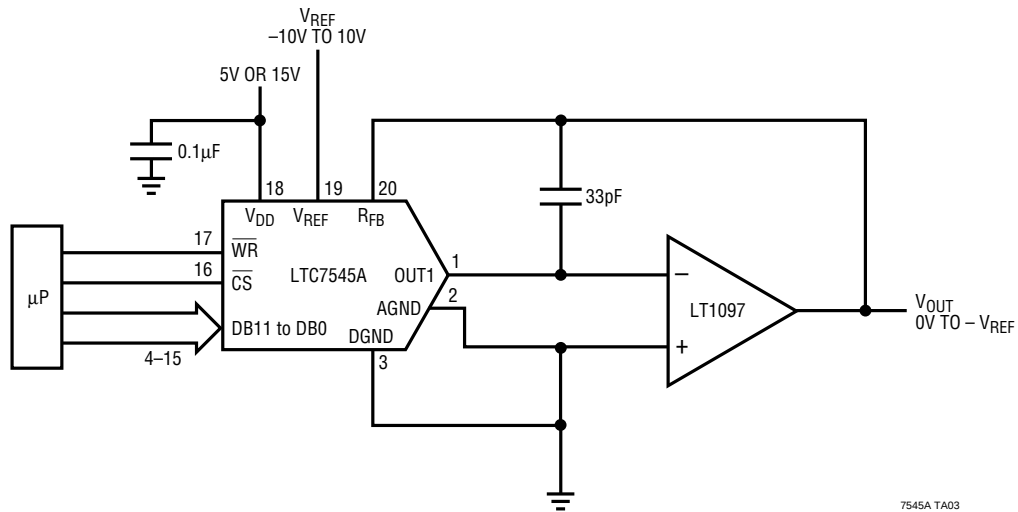


Table 1. Unipolar Binary Code Table

DIGITAL INPUT BINARY NUMBER IN DAC LATCH			ANALOG OUTPUT V_{OUT}
MSB		LSB	
1111	1111	1111	$-V_{REF}$ (4095/4096)
1000	0000	0000	$-V_{REF}$ (2048/4096) = $-V_{REF}/2$
0000	0000	0001	$-V_{REF}$ (1/4096)
0000	0000	0000	0V

TYPICAL APPLICATIONS

Bipolar Operation (4-Quadrant Multiplication)

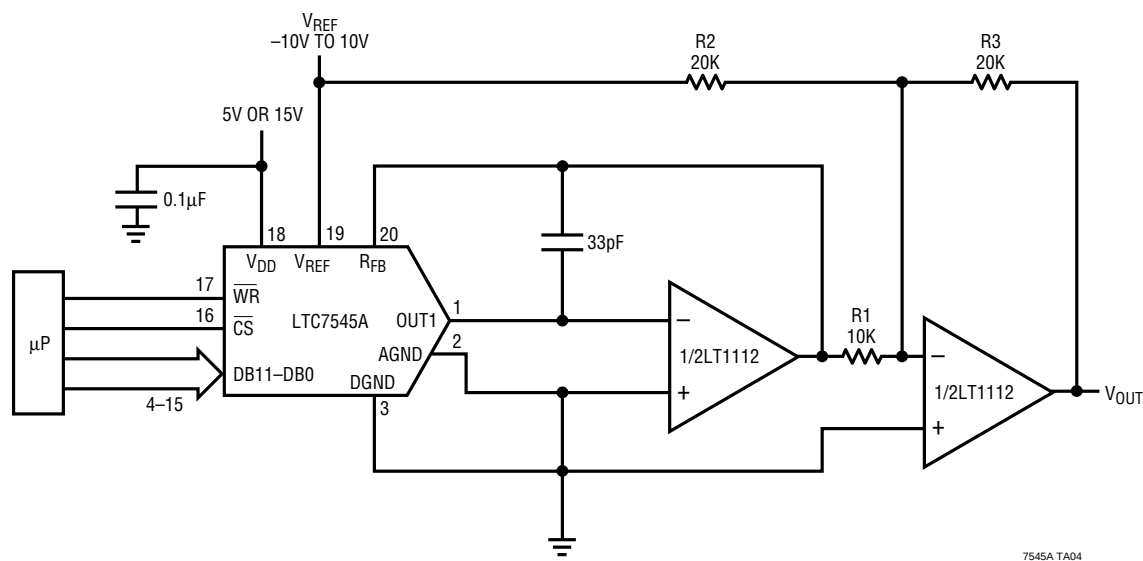


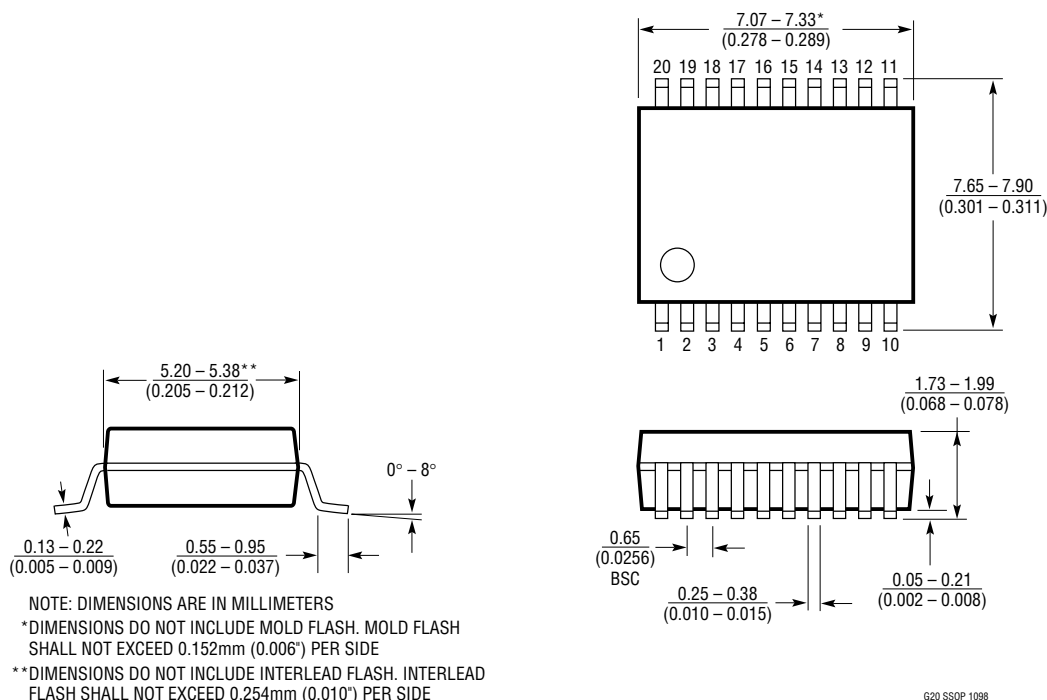
Table 2. Bipolar Offset Binary Code Table

DIGITAL INPUT BINARY NUMBER IN DAC LATCH			ANALOG OUTPUT V_{OUT}
MSB		LSB	
1111	1111	1111	V_{REF} (2047/2048)
1000	0000	0001	V_{REF} (1/2048)
1000	0000	0000	0V
0111	1111	1111	$-V_{REF}$ (1/2048)
0000	0000	0000	$-V_{REF}$ (2048/2048) = $-V_{REF}$

PACKAGE DESCRIPTION

Dimensions in inches (millimeters) unless otherwise noted.

G Package 20-Lead Plastic SSOP (0.209) (LTC DWG # 05-08-1640)



N Package 20-Lead PDIP (Narrow 0.300) (LTC DWG # 05-08-1510)

